

Design and expected performance of the ALICE ITS3 tracker upgrade

Jory Sonneveld on behalf of the ALICE collaboration

jory.sonneveld@nikhef.nl



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PALAIS DU PHARO
MARSEILLE, FRANCE



ALICE

Nikhef



UNIVERSITY
OF AMSTERDAM

Inner tracker: 3 layers, 22-42 mm from IP, 0.36% X_0
Outer tracker: 4 layers, 194-395 mm from IP, 1.1% X_0

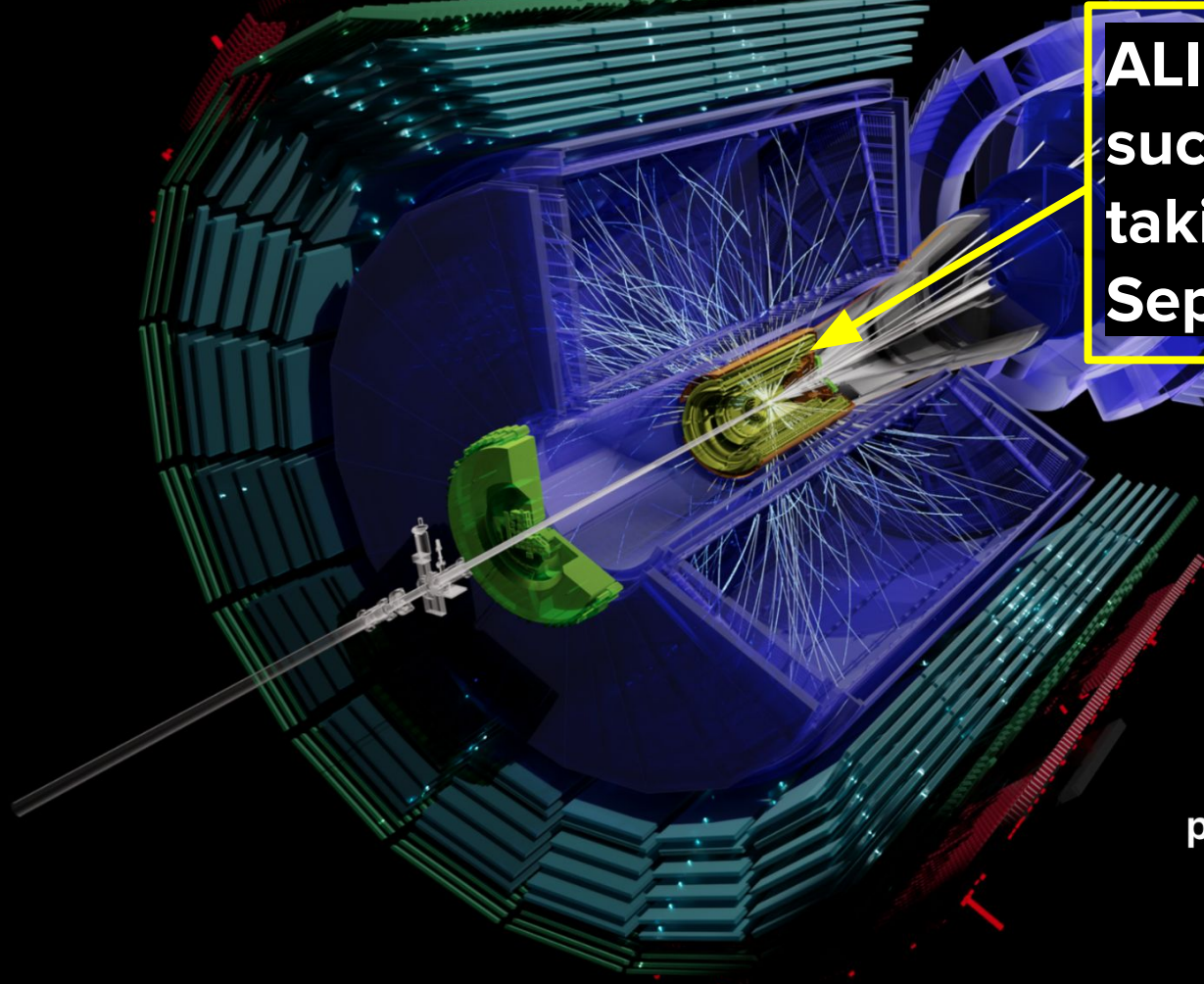


**Current ALICE inner
tracking system 2
(ITS2):**

**First monolithic
active pixel sensors
at LHC**

**pixels of
27 μm x 29 μm
resolution 5 μm**

**12.5 GPix 10 m² active area:
largest pixel detector ever built!**



**ALICE ITS2:
successfully
taking data since
September 2021**



ALICE

**LHC Run3
proton-Oxygen
1 July 2025**

ALICE: Quark gluon plasma in heavy ion collisions

Forward photons to prove
small-x initial gluons

**Low p_T heavy flavor
hadrons**

for heavy quark thermal
equilibrium

Low mass dilepton

precision measurements
for QGP temperature

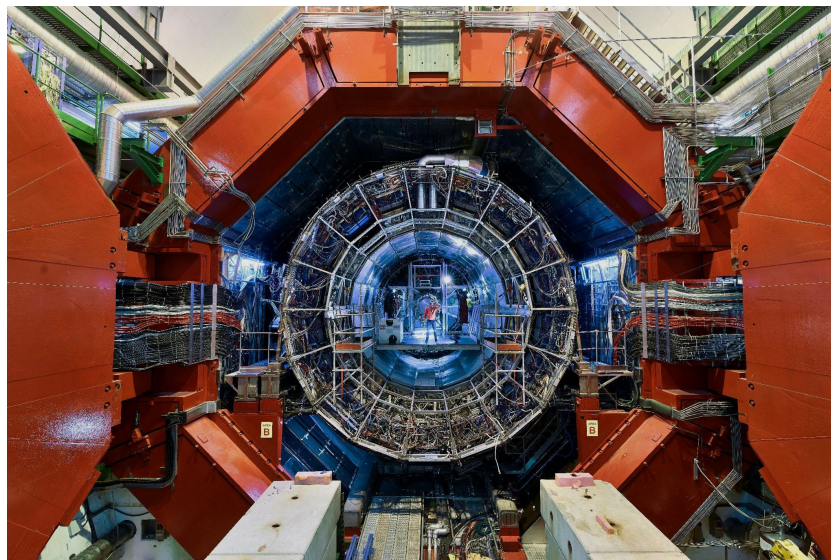


Image from cern.ch

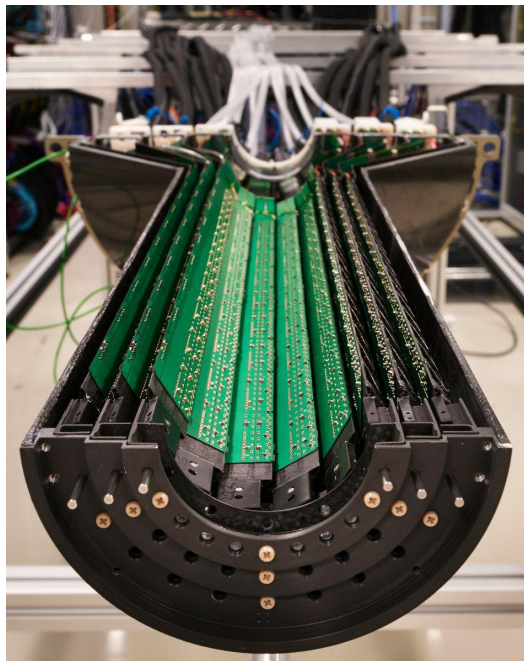
ALICE needs:

**Precise vertexing with high impact parameter resolution
Of $O(100)$ μm pointing resolution for 100 MeV charged
particles**

2028 upgrade of the ALICE inner tracking system



Currently: 0.36% X_0 per layer



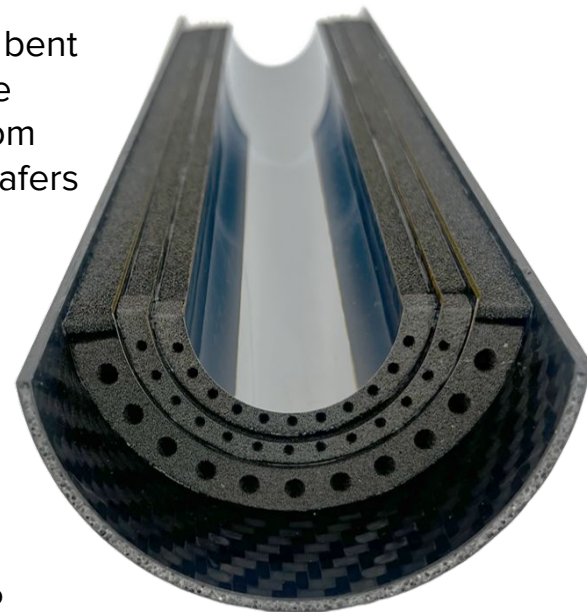
432 chips
from 200
mm
wafers

22.4 mm from IP
Beam pipe: 18 mm
radius, 800 μm Be
0.22% X_0

ITS2 inner barrel

Very low material budget! 0.09% X_0 per layer

6 stitched, bent
wafer-scale
sensors from
300 mm wafers



19 mm from IP
New beam pipe:
16.5 mm radius, 500 μm Be,
0.14% X_0

ALICE ITS3 for Run 4 in 2028

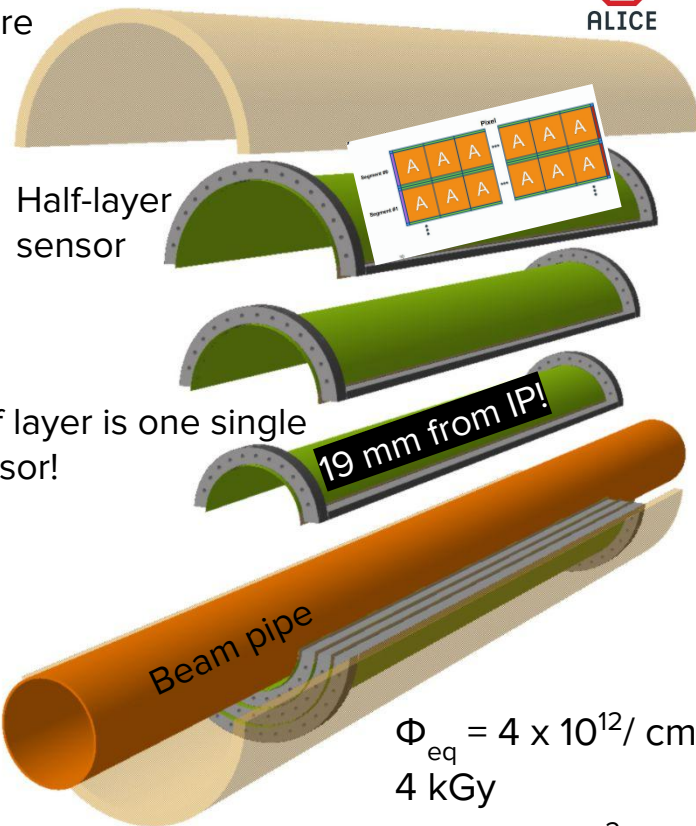


Stitching:

- Put design blocks together during processing of silicon
- Can make chip larger than the field of view of the lithographic equipment

- Material: $X/X_0 \approx 0.09\%$ average per layer
- 6 half-layer sensors with wafer-scale monolithic active pixel sensors (MAPS)
- Half layer sensor of size of $266 \times 58.7 \text{ mm}^2$ in layer 0
- Pixel size $22.8 \mu\text{m} \times 20.8 \mu\text{m}$
- Thinned to $50 \mu\text{m}$
- Mechanically held in place by carbon foam

Cylindrical support structure



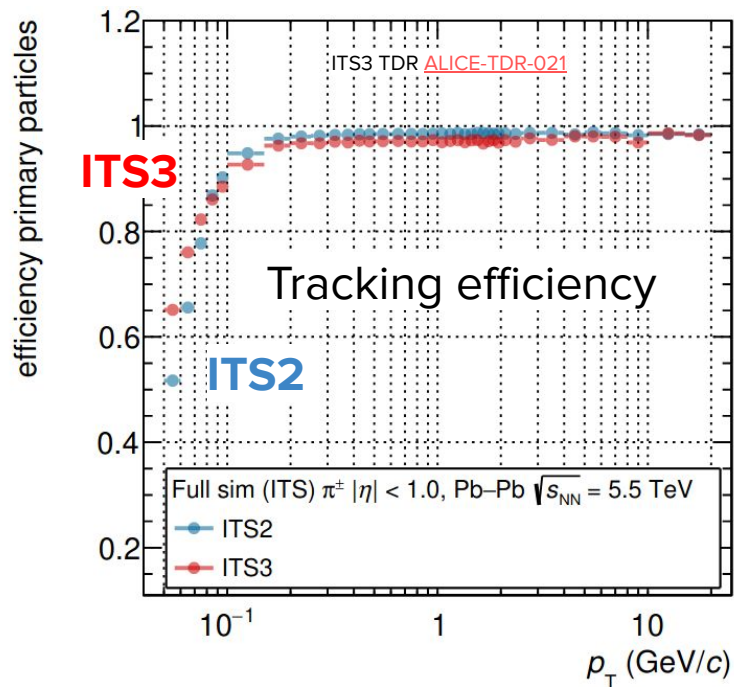
Each half layer is one single pixel sensor!

$$\Phi_{\text{eq}} = 4 \times 10^{12} / \text{cm}^2$$

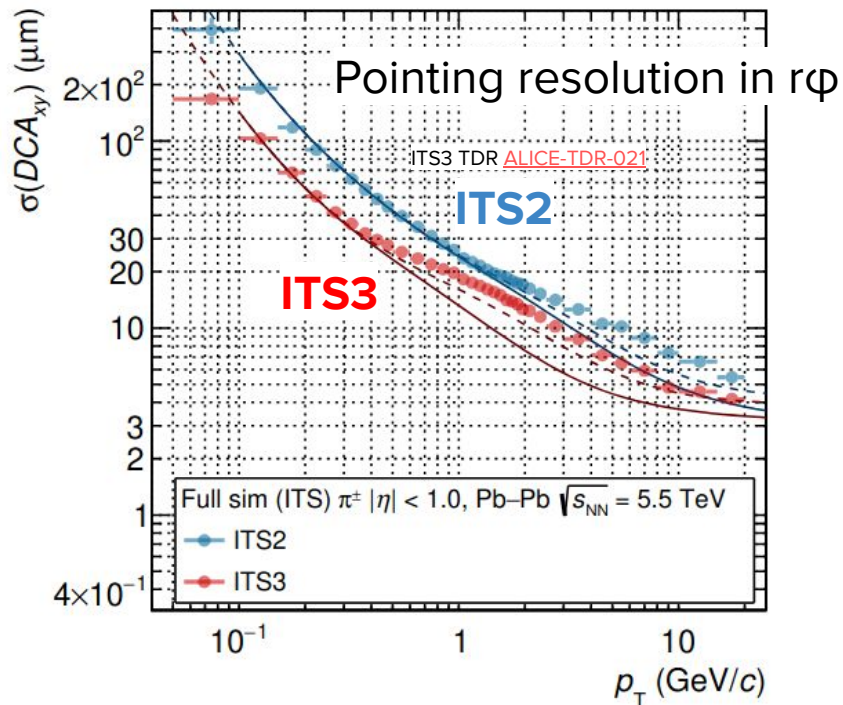
4 kGy
2.2 MHz/cm²

Improved measurements with more precise vertexing and tracking

ITS3: more precise vertexing and tracking



Large improvement at low p_T

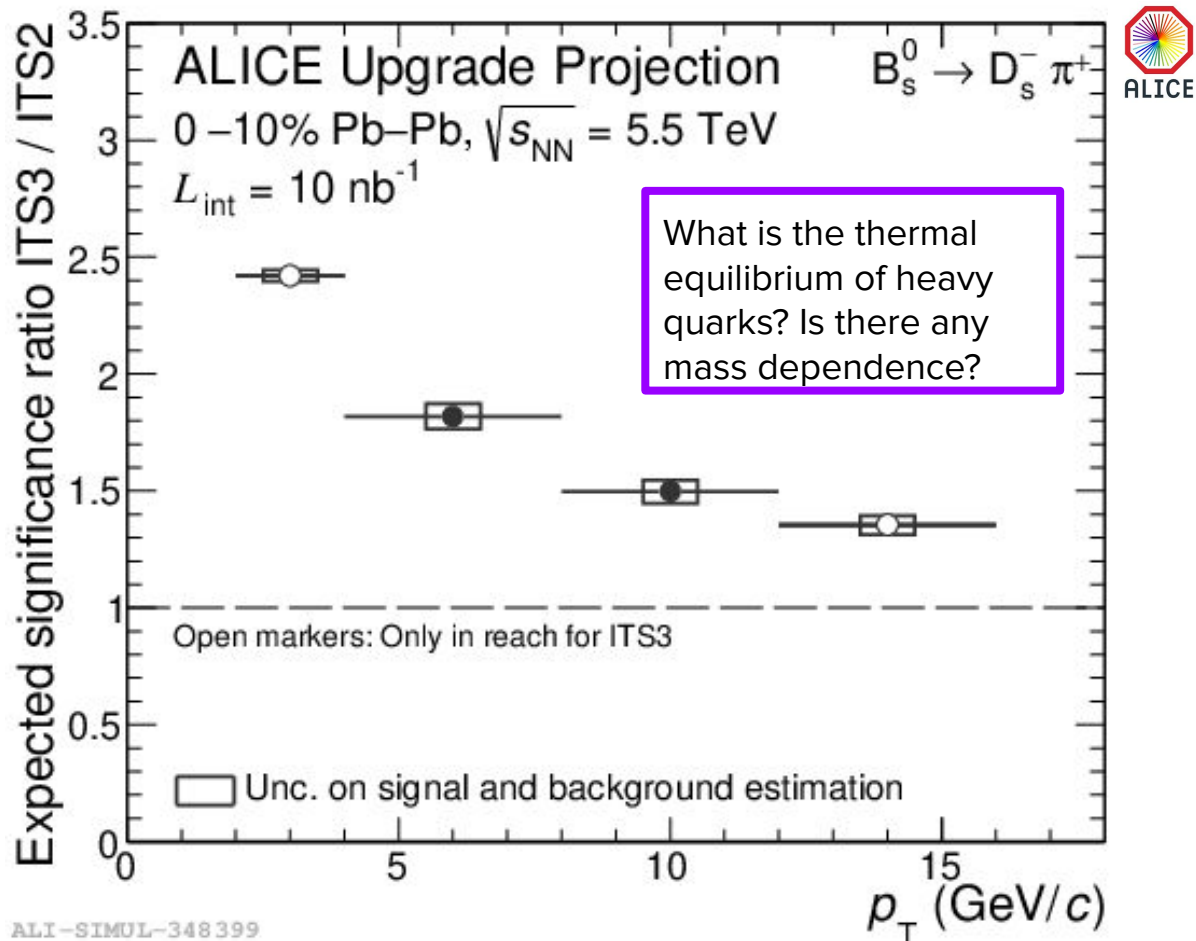


Factor 2 improvement over almost all momenta

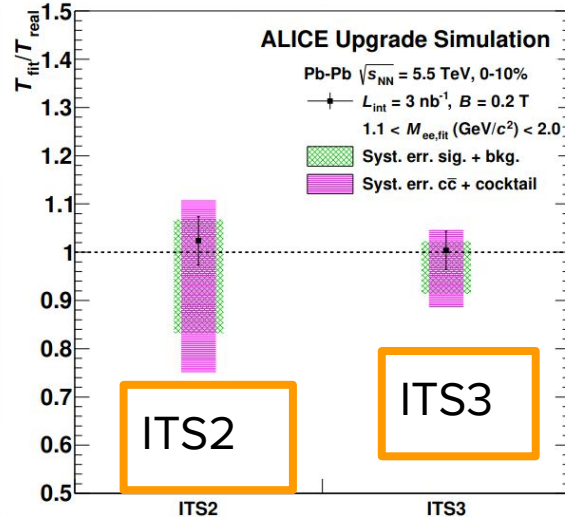
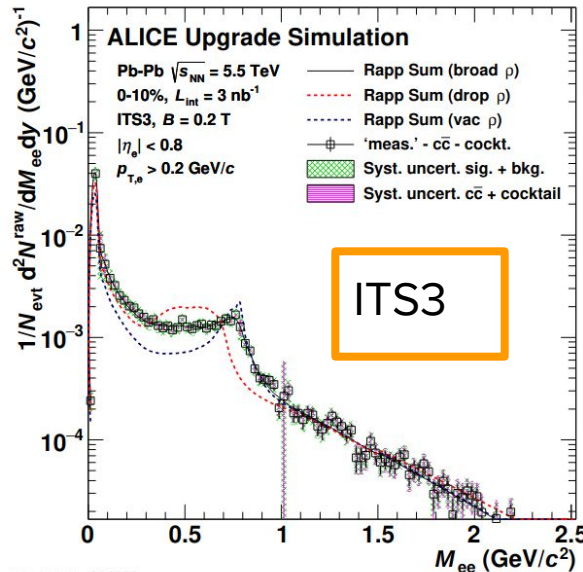
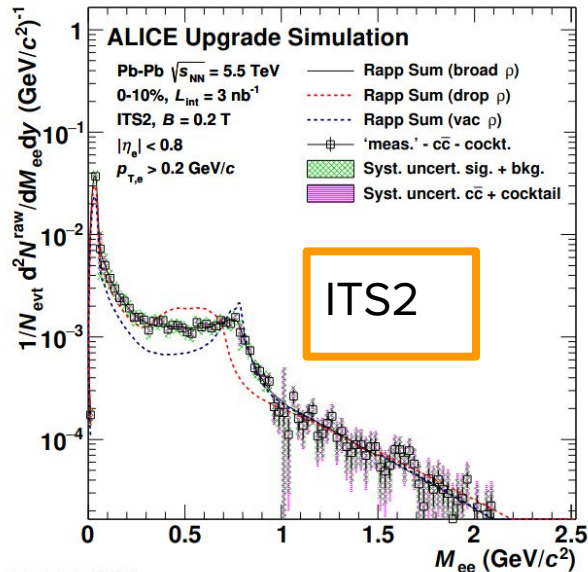
Strange beauty particles

- CMS made first measurement $B_S^0 / B_{\text{not } S}$ in Pb Pb collisions vs pp collisions – with large uncertainties
- ALICE similarly measured non-prompt Ds (Phys. Lett. B 846 (2023) 137561)
- Both see an enhancement
- No significant observation
- Large improvement with ITS3
- ITS3 can measure at **lower p_T**

This all thanks to a close proximity to IP and a very low material budget!



Thermal dielectrons



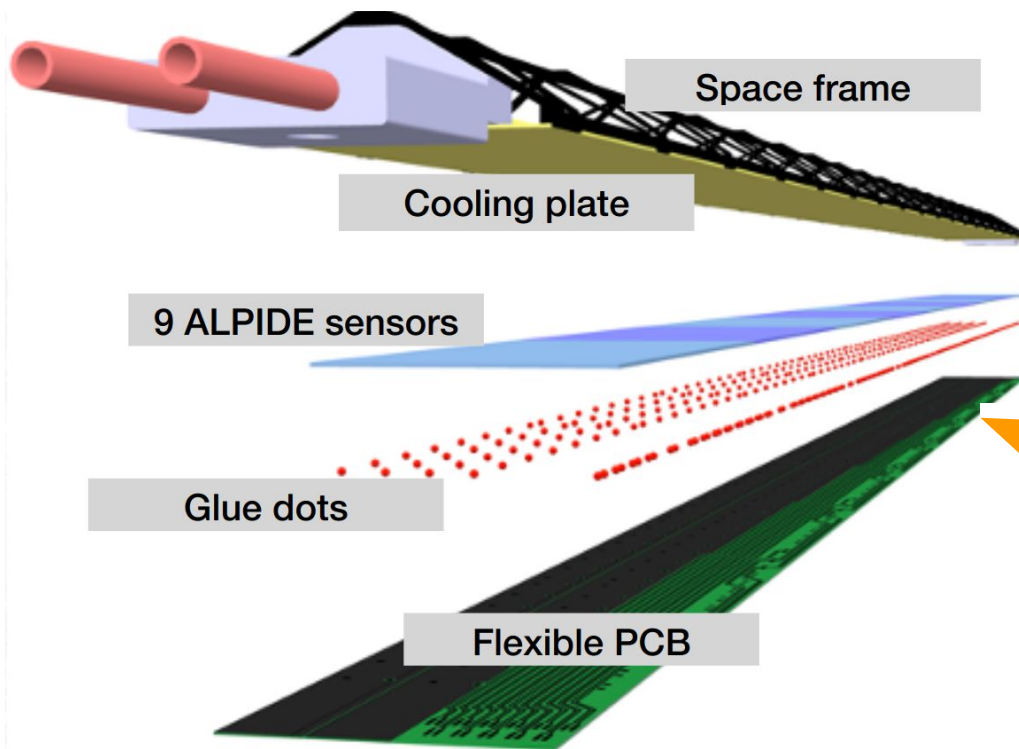
Syst. err down by factor 2

What is the temperature of the QGP radiation?

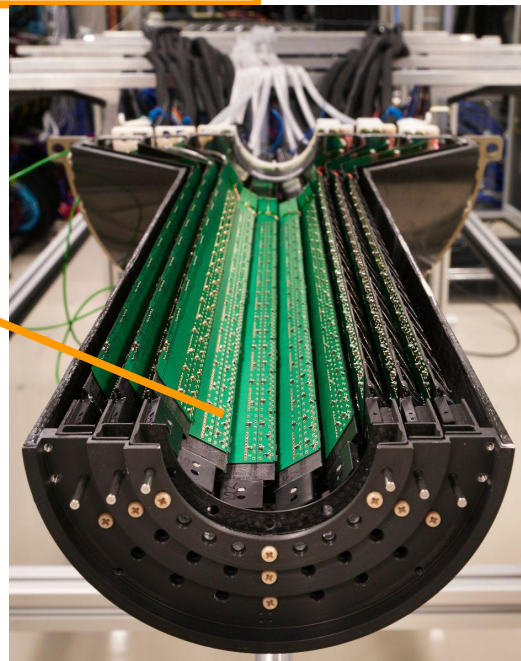
- ITS3 low-pT tracking improves photon conversion reconstruction efficiency
- Very good electron tagging efficiency with improved pointing resolution

How to reduce the material?

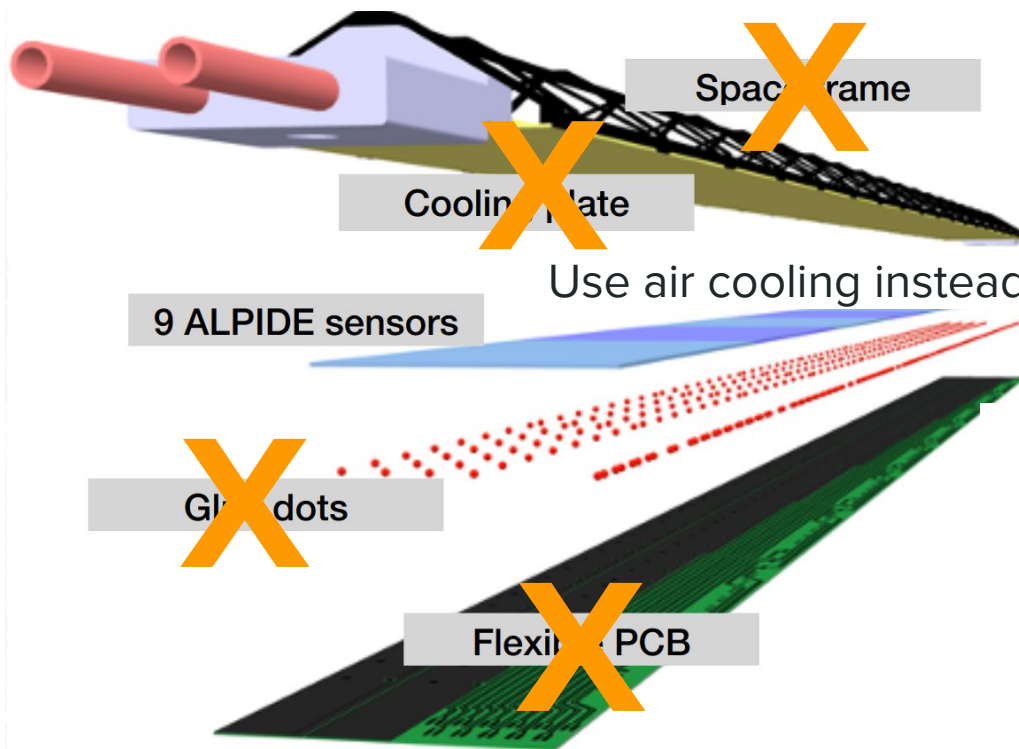
Remove “unnecessary” material from ITS2



Current ITS2
detector



Remove “unnecessary” material from ITS2

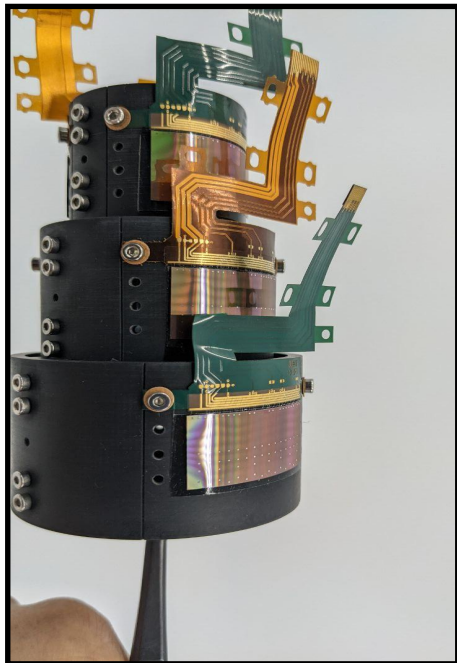


Less mechanical support needed for large bent sensors

Use air cooling instead of water. Requires $\sim 40 \text{ mW/cm}^2$

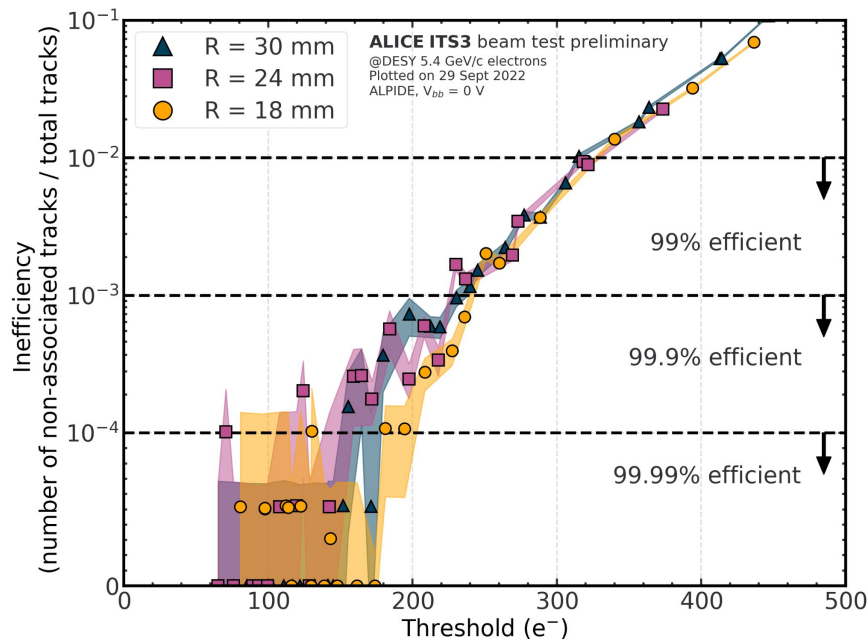
Power and data are integrated into silicon

Beam test studies with bent sensors



More results in [doi:10.1016/j.nima.2021.166280](https://doi.org/10.1016/j.nima.2021.166280)

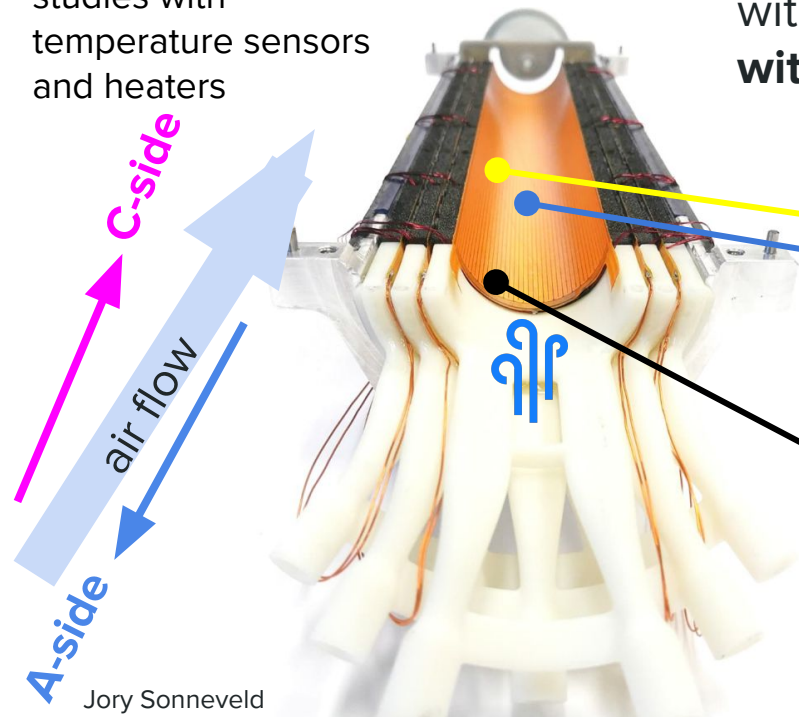
- Bending silicon wafers and functional ALPIDEs is now routine
- Full mock-up of the final ITS3: “ μ ITS3” bent to ITS3 radii tested
- Spatial resolution uniform among different radii
- Efficiency and resolution consistent with flat ALPIDEs



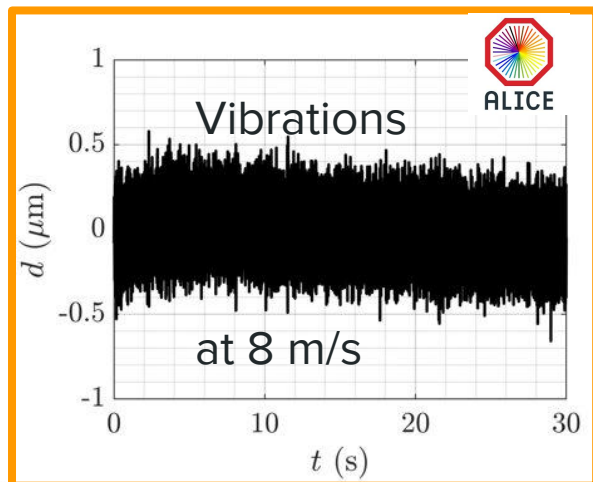
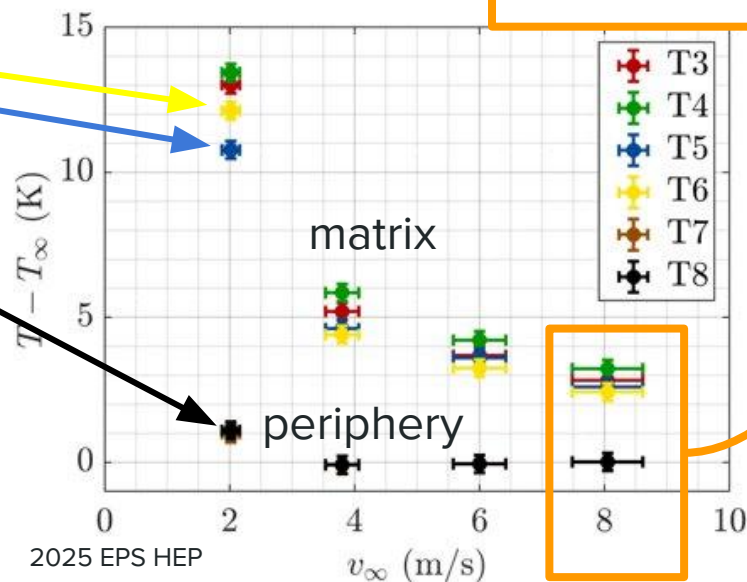
Performance under air cooling

Model for thermal studies with temperature sensors and heaters

Demonstrated air-cooling with vibrations **within 1 μm peak-to-peak**



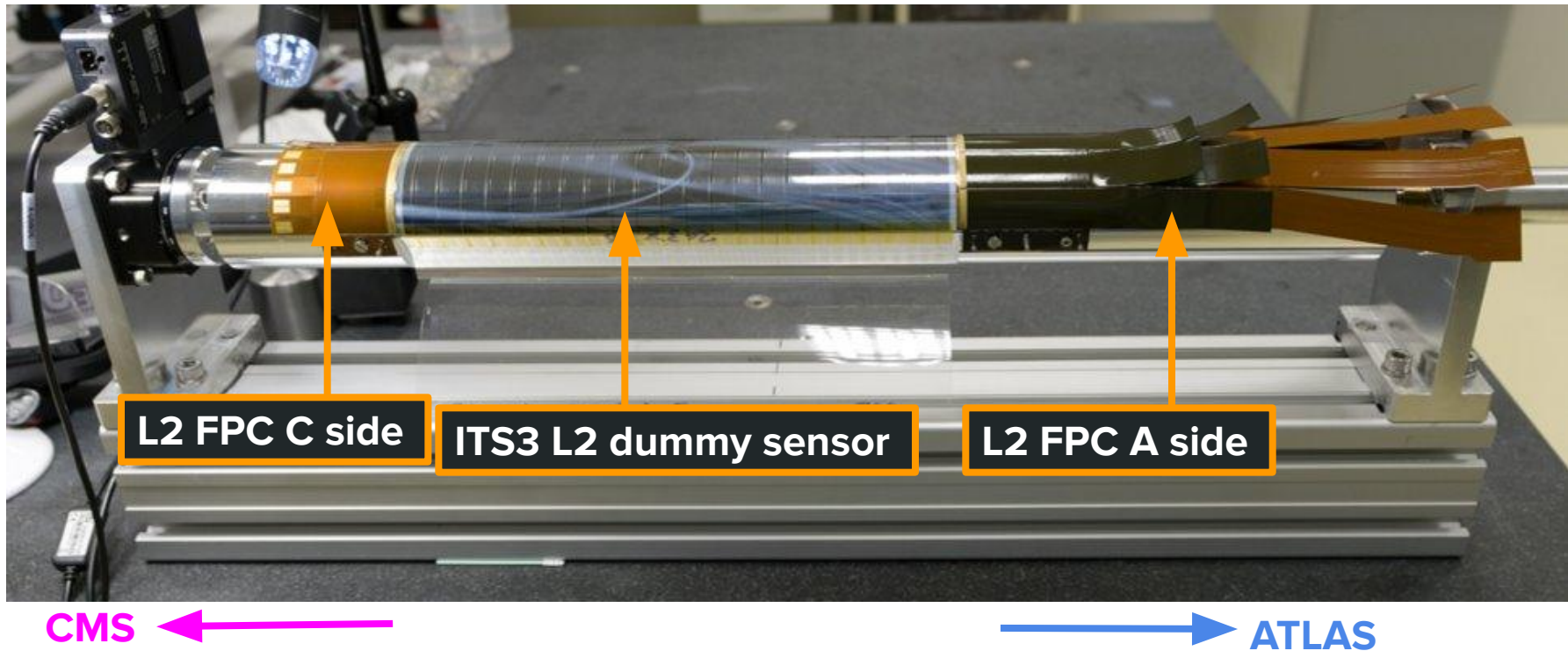
Jory Sonneveld



Silicon bending: full scale engineering model

C side: Powering

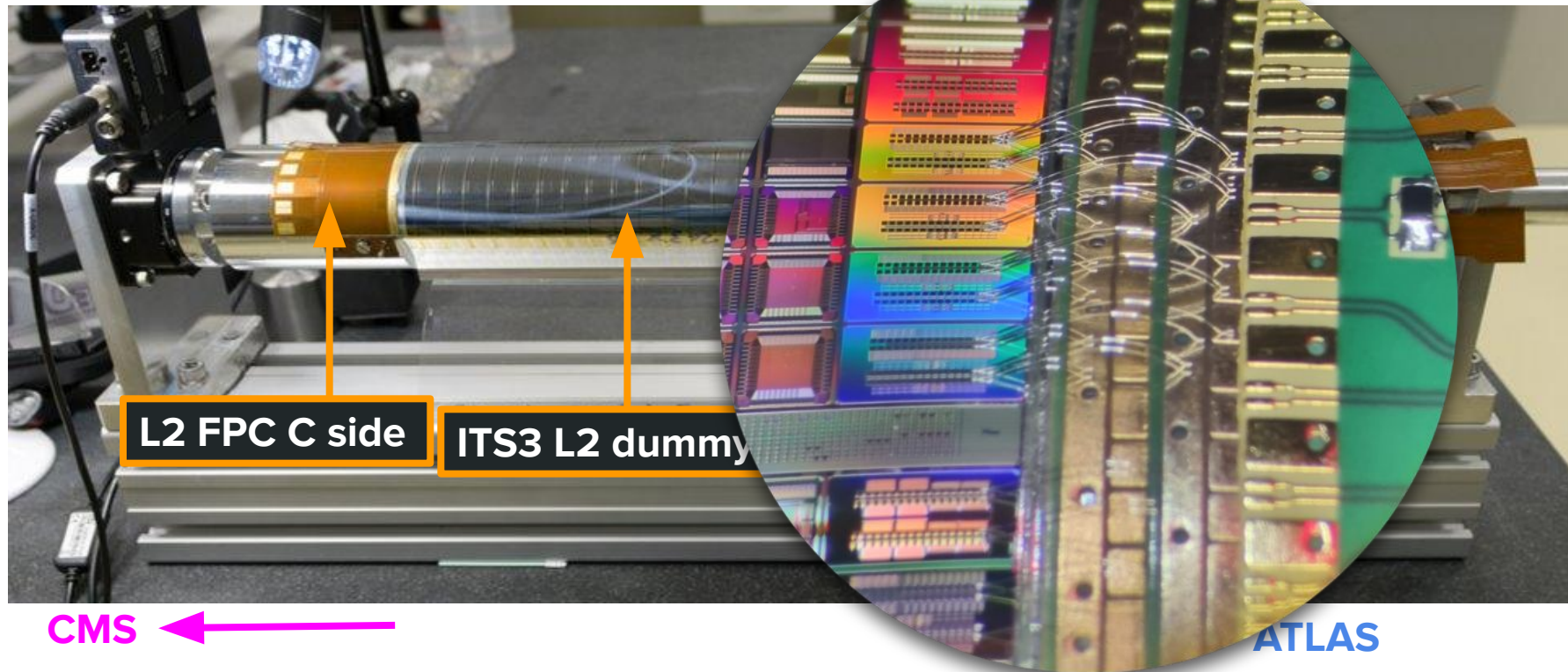
A side: Powering & data transmission



Silicon bending: full scale engineering model

C side: Powering

A side: Data transmission



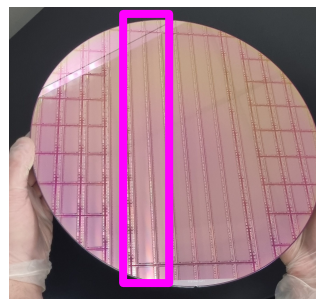
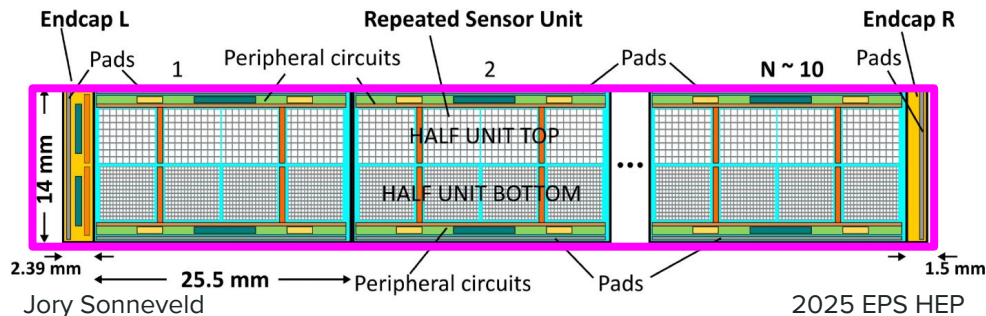
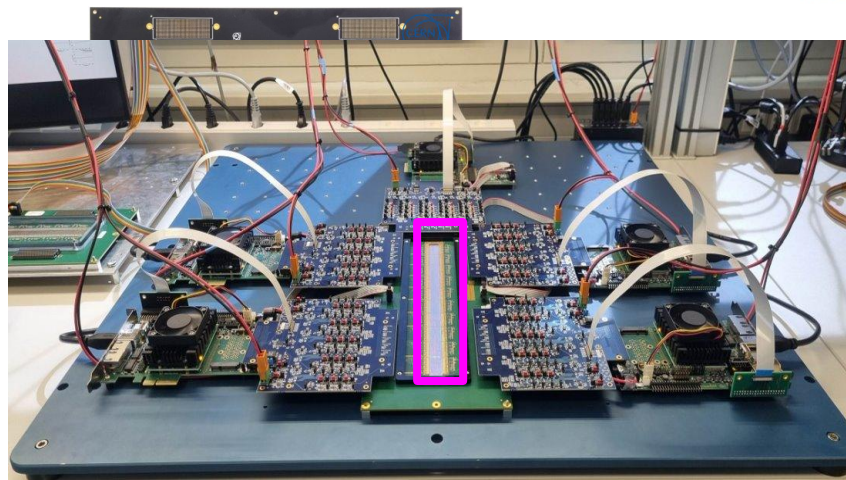
CMS ←

ATLAS

Sensor R&D

Stitched sensor prototypes

- TPSCo CIS 65 nm \rightarrow 300 mm wafers
- Engineering Run 1 (ER1):
 - Monolithic Stitched Sensor (MOSS)
 - with Timing (MOST)
- MOSS $14 \times 259 \text{ mm}^2$, 6.72 MPixel
- MOST $2.5 \times 259 \text{ mm}^2$, 0.9 MPixel
- Final structure 2.5 times as large
- Pixels of $22.5 \times 22.5 \mu\text{m}^2$ and $18 \times 18 \mu\text{m}^2$
- Processing issue found:
 - understood, and fixed for next submission
- Yield in unaffected sensors $> 90\%$
 - \rightarrow failure tolerant structures



65 nm technology:

Validated to ITS3 fluences:

[Nucl.Instrum.Meth.A, 1069 \(2024\) 169896](#)

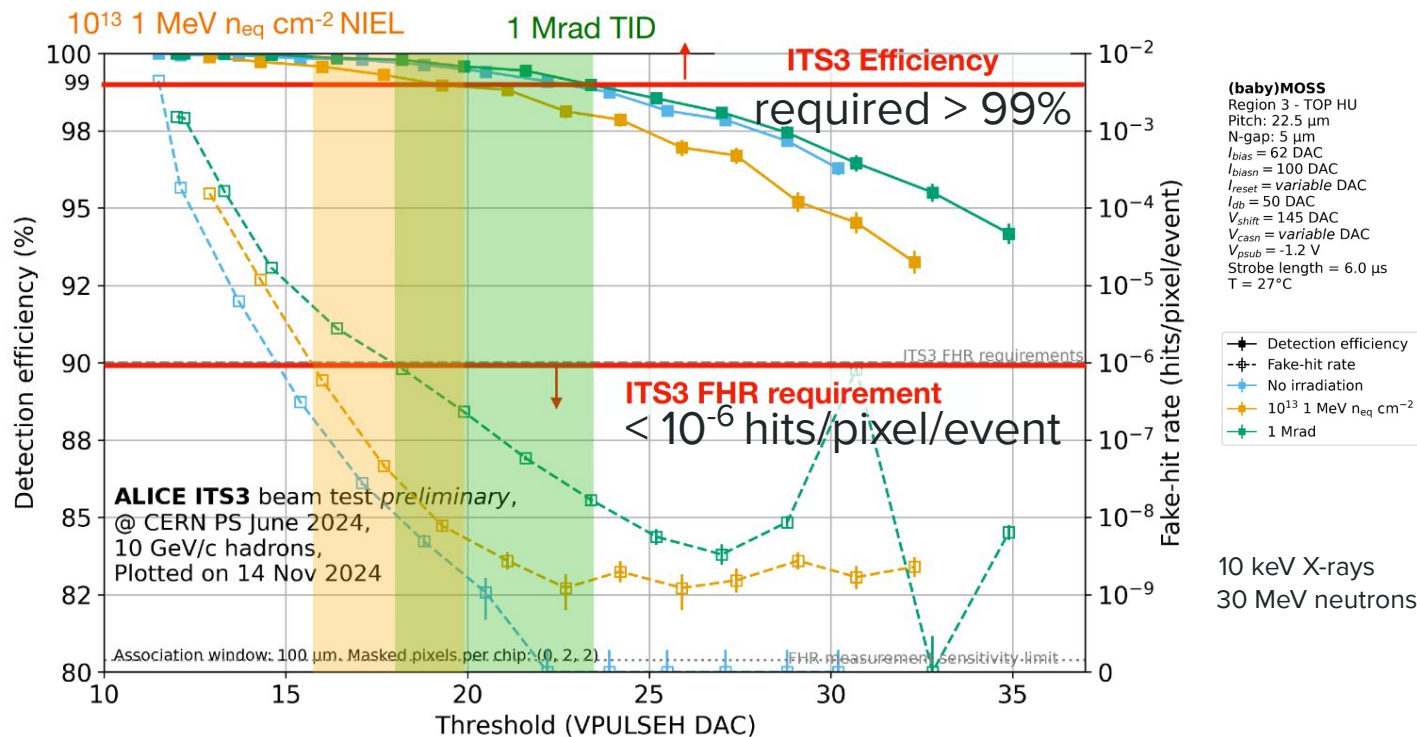
Time resolution 67 ps:

[Nucl.Instrum.Meth.A, 1070 \(2025\) 170034](#)

Validation of digital test structure:

[Nucl.Instrum.Meth.A, 1056 \(2023\) 16858](#)

Performance of 259 mm stitched sensors



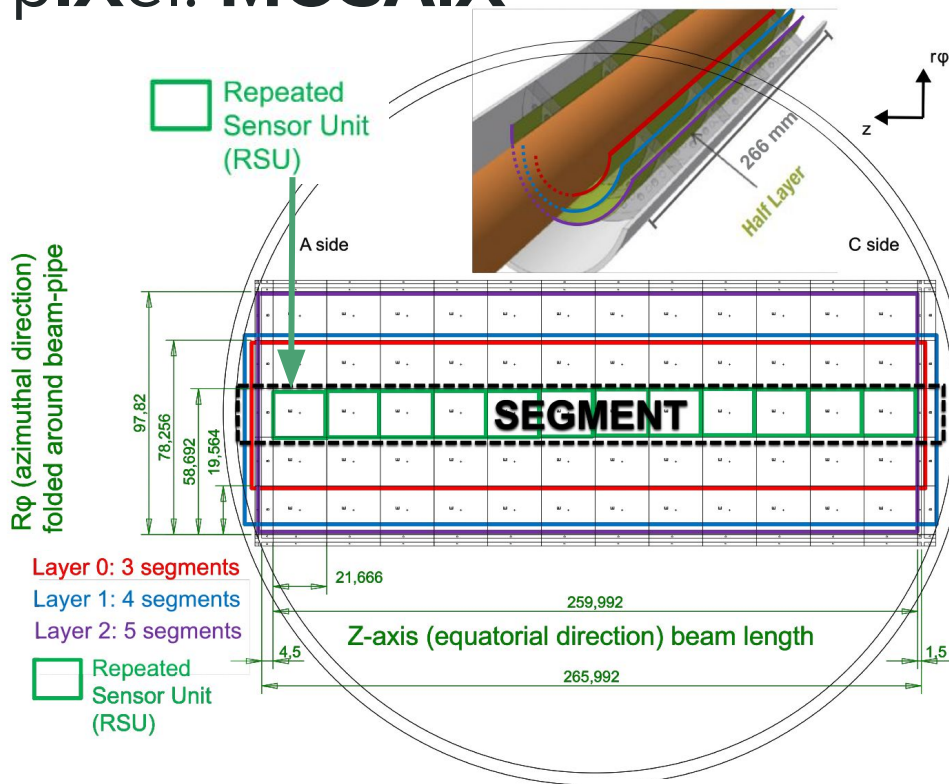
- 82 days of in-beam data
- 17 chips
- 2 process variations
- 5 irradiation levels
- Many settings

10 keV X-rays
30 MeV neutrons

- Fully functional 259 mm stitched sensor even after irradiation
- ITS3 requirements met at 4×10^{12} 1 MeV n_{eq} cm⁻² and 400 krad

MOⁿolithic Stⁱched Ac^tive p^IXel: MO^SAIX

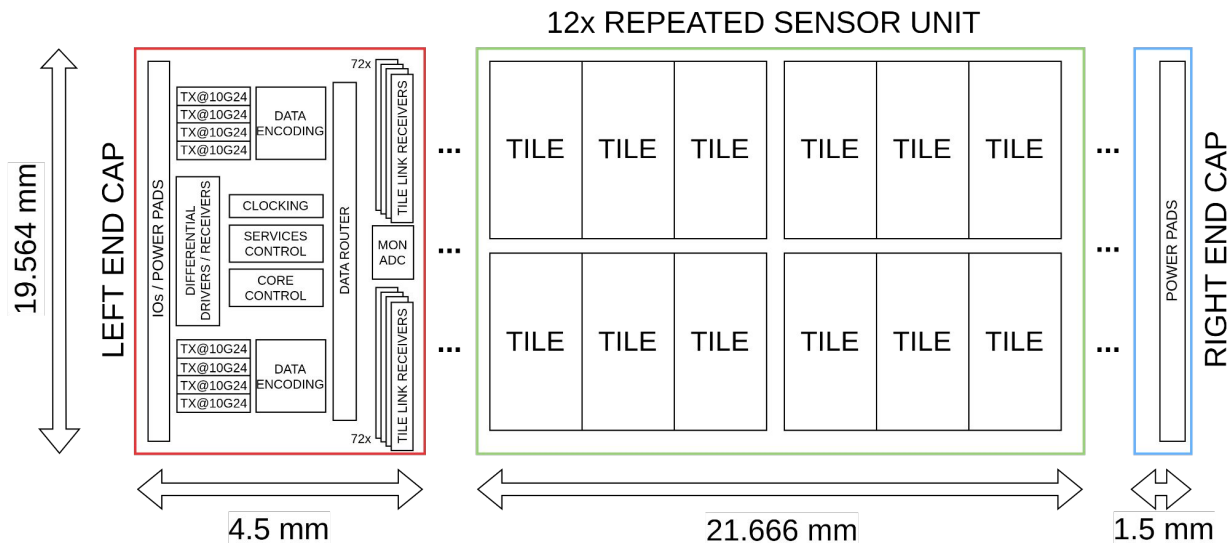
- R&D towards ITS3:
Engineering Run 2 MO^SAIX
- Final prototype before ITS3 production to be tested with bending
 - Includes features of both MO^SSS and MO^ST
- MO^SAIX has modular design: 3, 4, or 5 segments for layers 0-2



MOSAIX sensitive area and powering scheme

Readout
through **left**
end cap

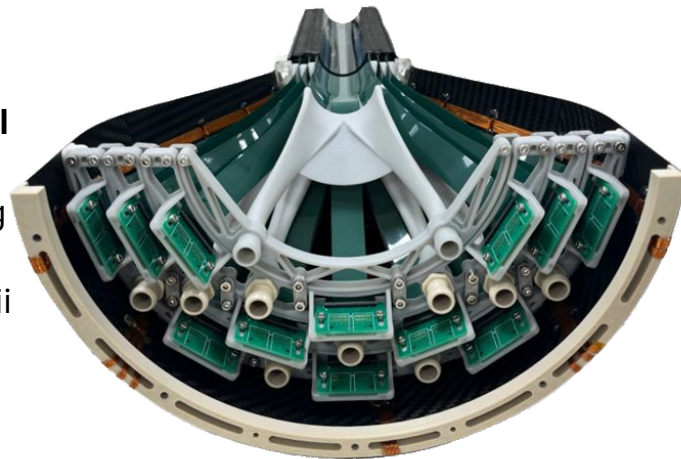
Powering
through **LEC**
and **REC**



- 12 RSUs, **12 tiles per RSU** with independent powering, control, and readout
- 144 tiles → 0.7% of sensor per tile that can be switched off individually in case of a short or issue
- 93% sensitive area in total

Summary and outlook

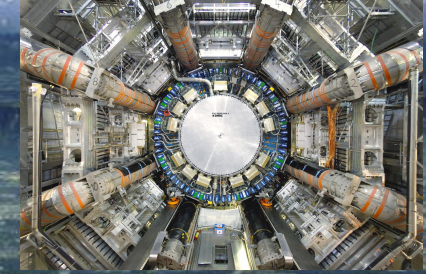
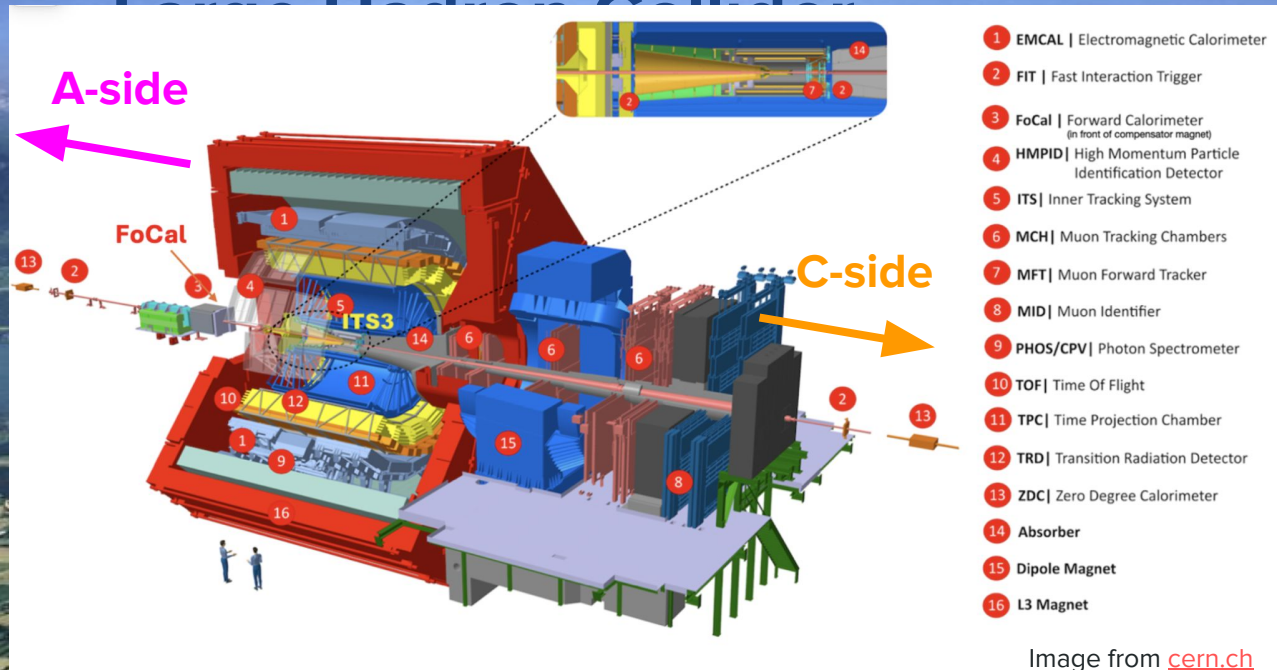
- ALICE will install **new inner layers for ALICE inner tracking system 3 (ITS3)** for LHC Run 4 in 2028
- Aim for **truly cylindrical wafer-scale monolithic active pixel sensors**
- **Silicon flexibility and bending proven** with routine bending tests
- **Full mockup of ITS3 efficient** when bent to ITS3 target radii



- Sensor prototypes reach **>99% detection efficiency and less than 10^{-6} hits/pixel/event fake hit rate** at room temperature **at ITS3 fluence requirement** of $\Phi_{eq} = 4 \times 10^{12} / \text{cm}^2$
- **First stitched sensors successfully tested**, final prototype coming next year
- ITS3 R&D will pave the way to thin 50 μm low-power 40 mW/cm² sensors that **could be used in ALICE 3** (see [talk by Antonin Maire in this session](#)) and beyond at FCC

ITS3 is a successful R&D project enabling a wealth of new precision measurements.

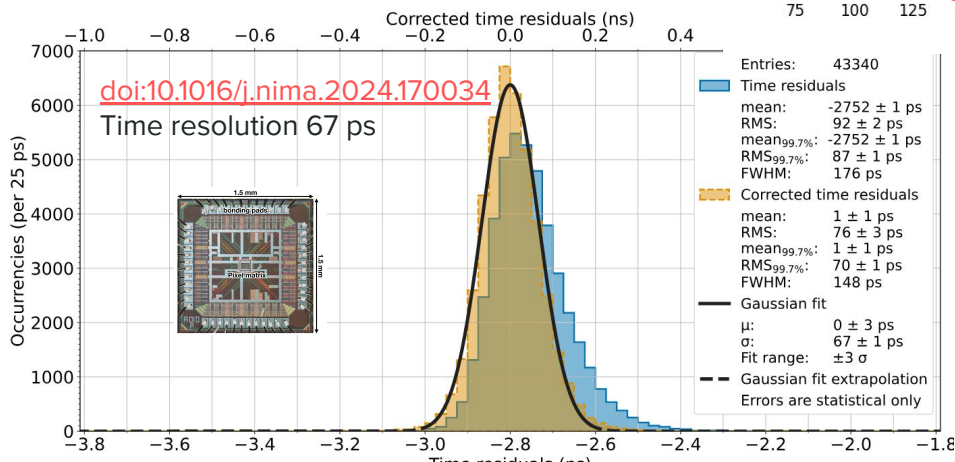
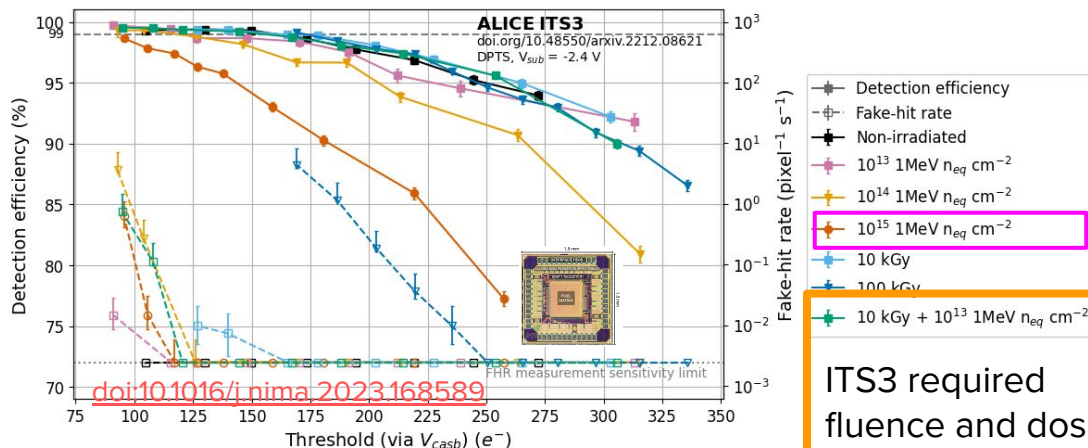
Additional material



LHC 27 km

Qualification of new 65 nm technology for ITS3

- Multi-Layer Reticle 1 (MLR1): first submission in Tower Partner Semiconductor (TPSCo) 65 nm technology
- 65 nm wafers are 300 mm: allows for large scale sensors
- 55 small-scale analog and digital pixel test structure variants of processes and pitches



Validated for

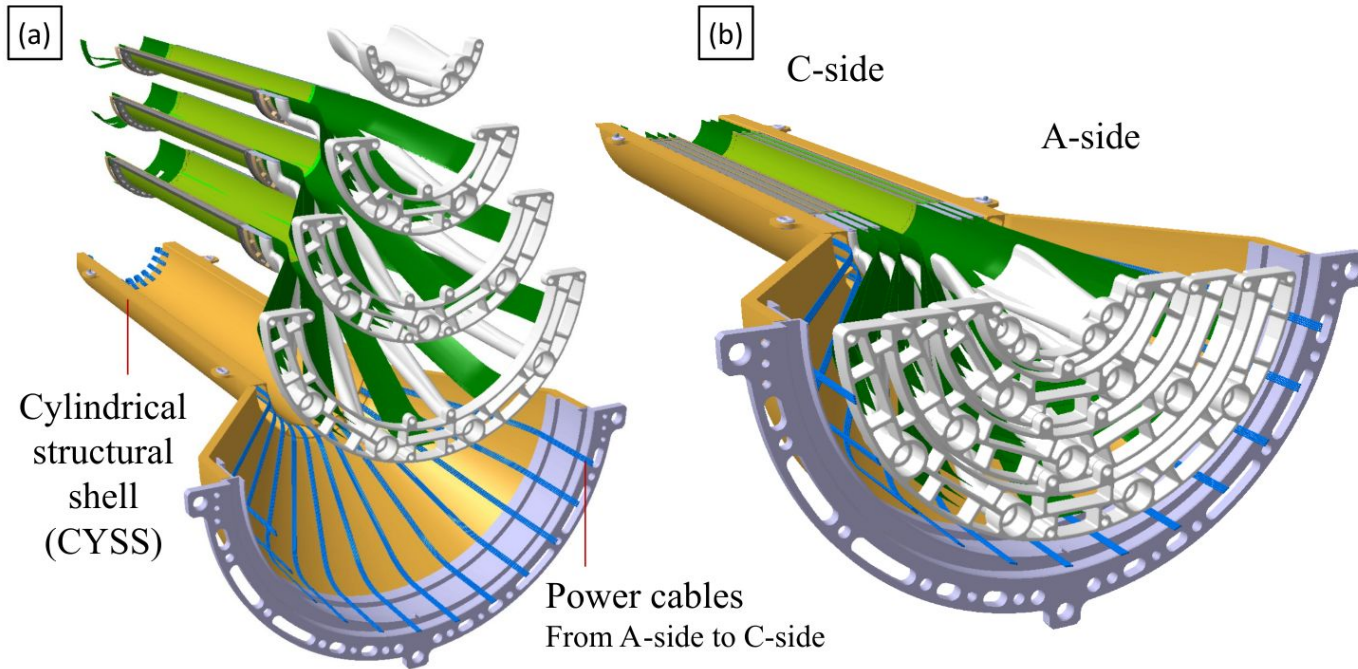
- charge collection efficiency
- detection efficiency
- radiation hardness

See also

doi:10.1016/j.nima.
2024.169896

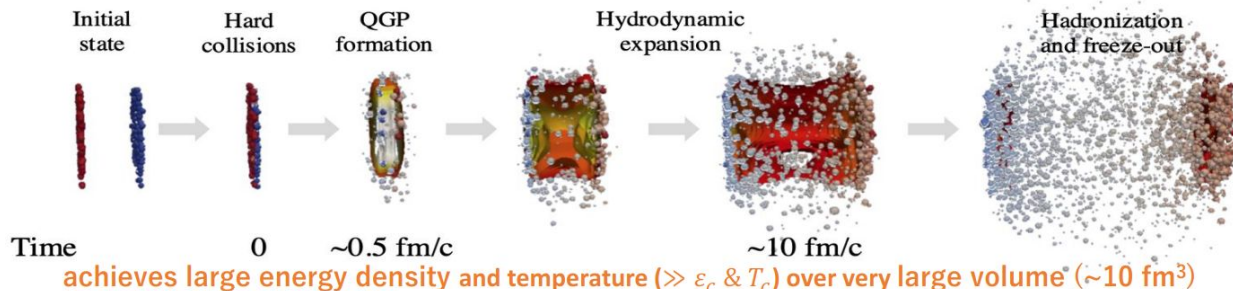
Sensor still operable at 99% efficiency at 20°C after $\Phi_{eq} = 10^{15} / \text{cm}^2$!

Powering ITS3



Power lines travel along CYSS to reach the C-side

ALICE: Quark gluon plasma in heavy ion collisions



Some open questions:

<https://arxiv.org/pdf/1804.06469>

Forward photons to prove small-x initial gluons

What is the initial state of collisions and QGP formation?
Is the gluon density saturated at small x?

Low p_T heavy flavor hadrons

What is the thermal equilibrium for heavy quarks? What is the mass dependence?

Low mass dilepton
precision measurements

What is the temperature of QGP radiation?
How is chiral symmetry restored in QGP?

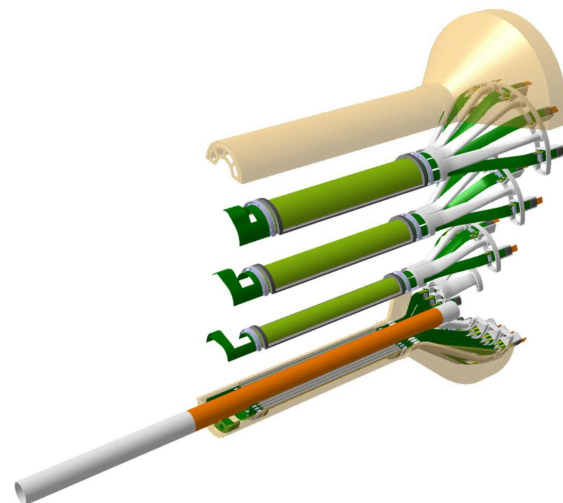
From [Ken Oyama](#)

ITS3 geometry

Table 2.1: ITS3 general parameters.

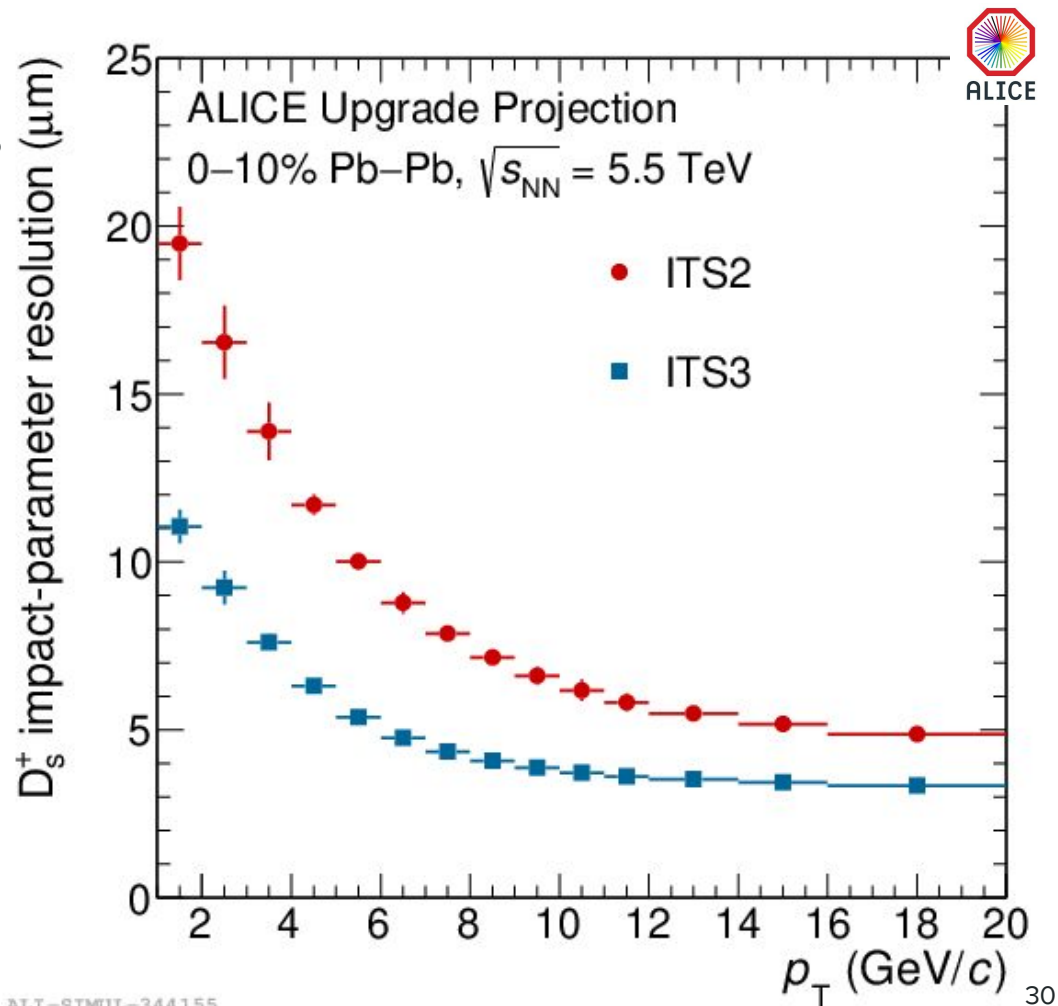
Beampipe inner/outer radius (mm)	16.0/16.5		
IB Layer parameters	Layer 0	Layer 1	Layer 2
Radial position (mm)	19.0	25.2	31.5
Length (sensitive area) (mm)	260	260	260
Pseudo-rapidity coverage ^a	± 2.5	± 2.3	± 2.0
Active area (cm ²)	305	407	507
Pixel sensors dimensions (mm ²)	266×58.7	266×78.3	266×97.8
Number of pixel sensors / layer	2		
Material budget (% X_0 / layer)	0.07		
Silicon thickness (μm / layer)	≤ 50		
Pixel size (μm^2)	$O(20 \times 22.5)$		
Power density (mW/cm ²)	40		
NIEL (1 MeV n_{eq} cm ⁻²)	10^{13}		
TID (kGray)	10		

^a The pseudorapidity coverage of the detector layers refers to tracks originating from a collision at the nominal interaction point ($z = 0$).



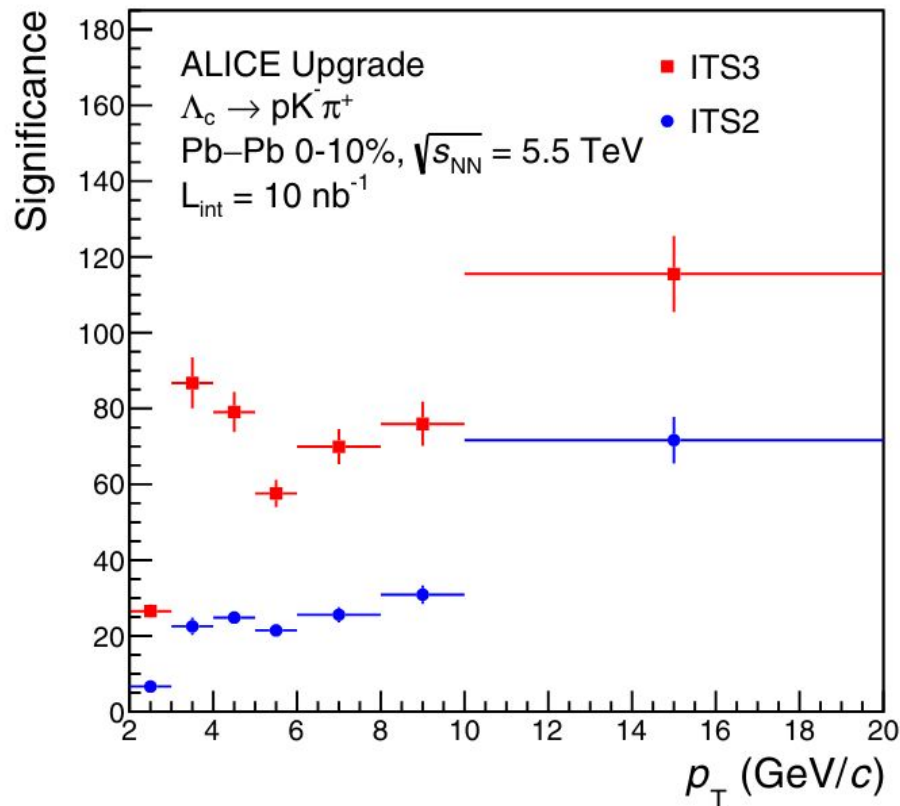
Non-prompt D mesons

- Highly sensitive to beauty-strange hadron production in quark gluon plasma
- $\text{Br}(B_s^0 \rightarrow D_s^+ + X) = (93 \pm 25)\%$
- Higher background rejection resulting from improved track spatial resolution

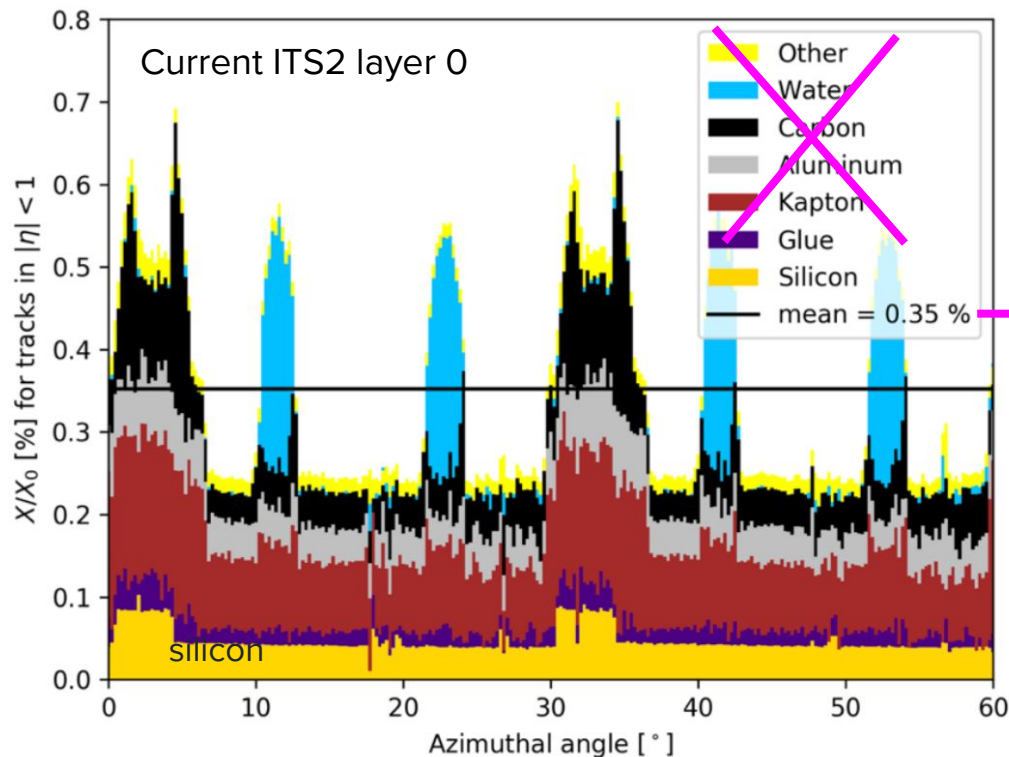


Better reconstruction of short-lived hadrons in ITS3

- Short lifetime:
 $c\tau(\Lambda_c^+) \sim 59 \mu\text{m}$
twice smaller than D^0 meson
- Decay tracks displaced $O(10) \mu\text{m}$ from IP
- Significance of Λ_c in pion decay channel more than doubles in ITS3 for low momenta



Remove “unnecessary” material from ITS2

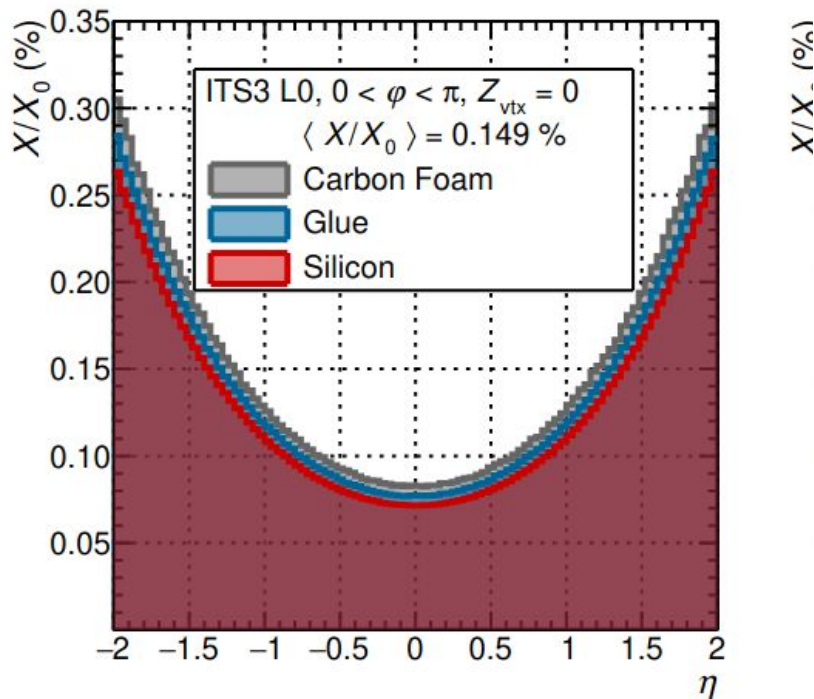


- Circuit board (kapton, aluminum): not required if power and data are integrated into the silicon

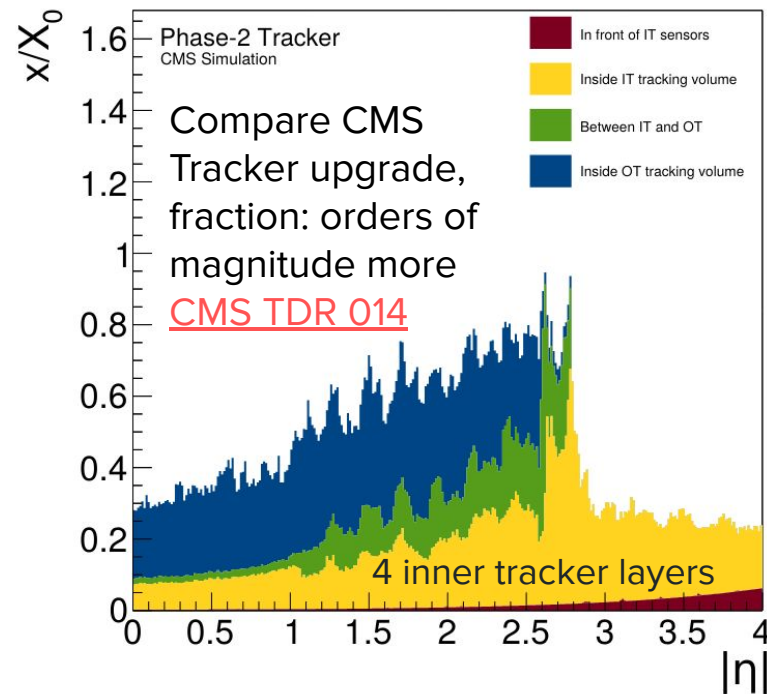
Mean 0.05% per layer

- Water cooling → replace with air cooling. Requires $< 40 \text{ mW/cm}^2$
- Less mechanical support (carbon, glue) needed for large, bent sensors!

Remove “unnecessary” material from ITS2

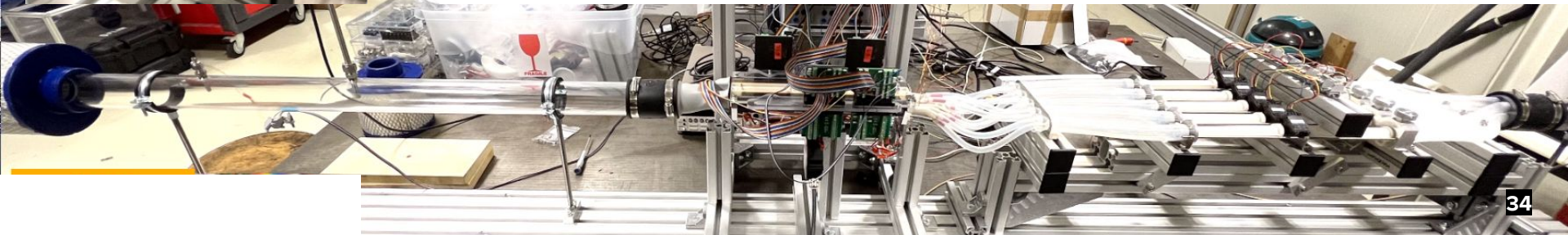
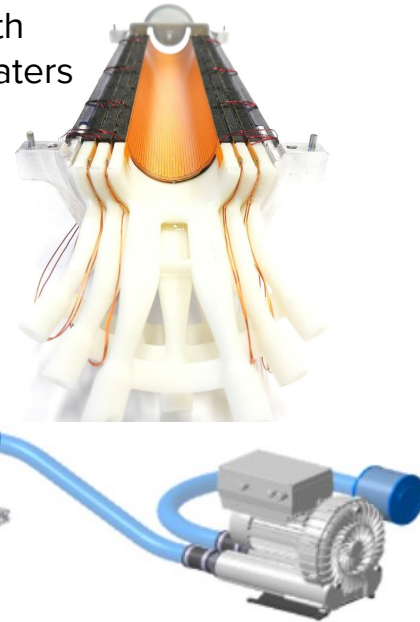
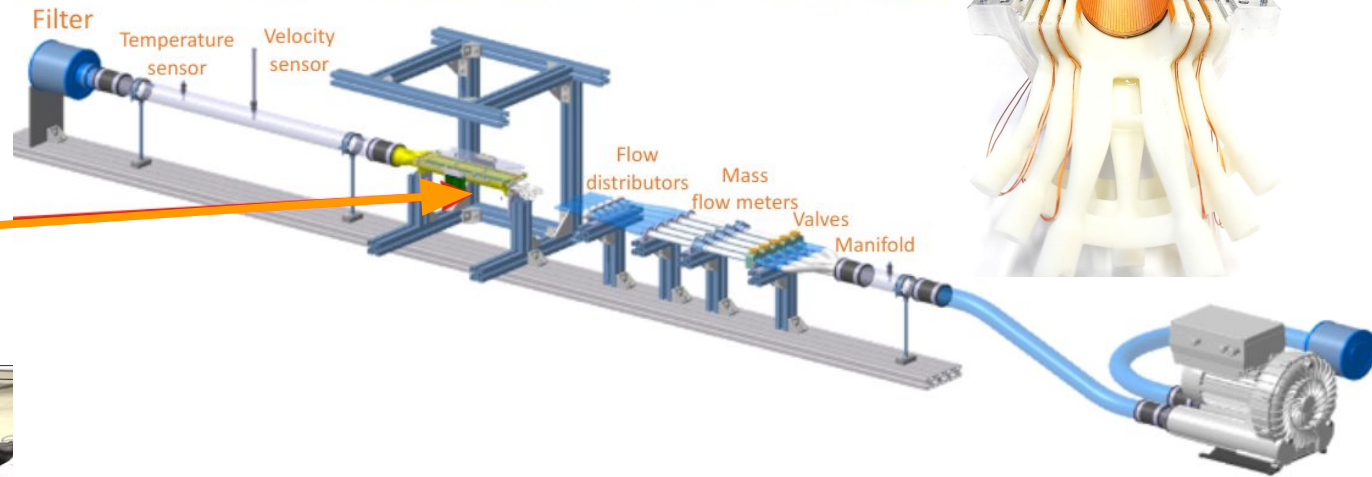


ITS3 TDR



Air cooling test system

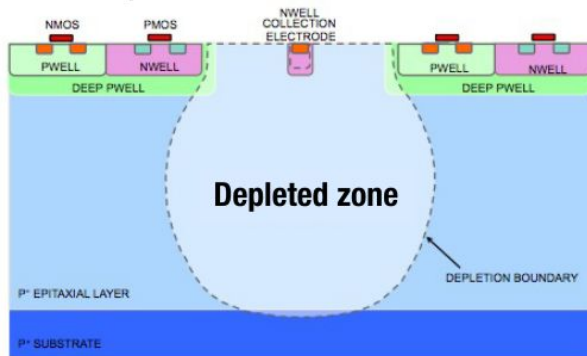
Model for thermal studies with temperature sensors and heaters



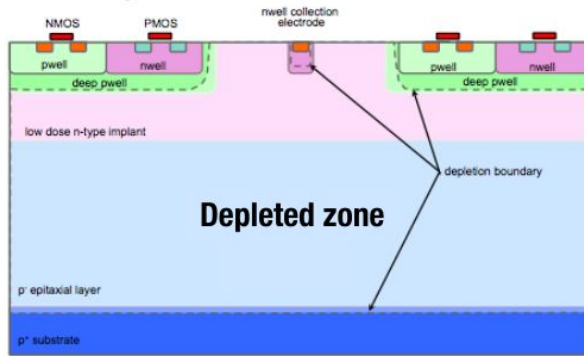
Different process modifications

- Motivated by better charge collection
- Higher speed may serve for monolithic sensors with timing functionality that could be applied in ALICE3

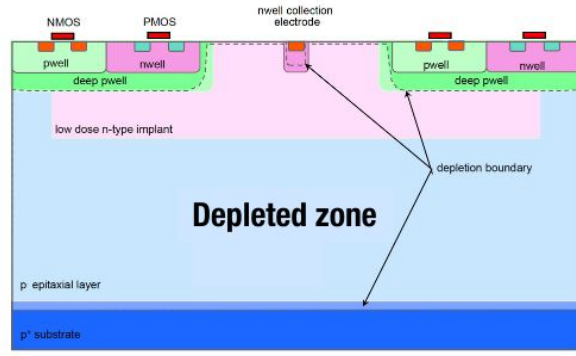
Standard process



Modified process



Modified process with gap



Charge sharing

Charge Collection efficiency and speed